



30V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
	3.2mΩ @ V _{GS} = 10V	100A
30V	5.5mΩ @ V _{GS} = 4.5V	85A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

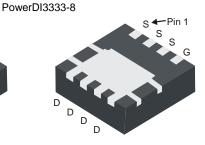
- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- Excellent Q_{GD} × R_{DS(ON)} Product (FOM)
- Advanced Technology for DC-DC Converters
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- 100% Unclamped Inductive Switching, Test in Production Ensures More Reliable And Robust End Application
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

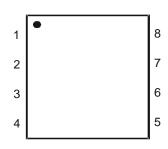
- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)



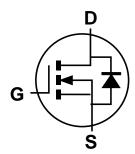




Bottom View



Top View Internal Schematic



Equivalent Circuit

Ordering Information (Note 5)

Part Number	Case	Packaging
DMT3003LFGQ-7	PowerDI3333-8	2,000/Tape & Reel
DMT3003LFGQ-13	PowerDI3333-8	3,000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



SG2 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	30	V	
Gate-Source Voltage	V_{GSS}	±20	V	
Continuous Drain Current (Note 7) V _{GS} = 10V	$T_C = +25$ °C $T_C = +70$ °C	I _D	100 90	А
Continuous Drain Current (Note 6) V _{GS} = 10V	I _D	22 18	А	
Maximum Continuous Body Diode Forward Current (Note 6)	I _S	3	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	100	Α	
Avalanche Current, L=1mH	I _{AS}	16	Α	
Avalanche Energy, L=1mH	E _{AS}	250	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T _A = +25°C	P_{D}	2.4	W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	52	°C/W	
Total Power Dissipation (Note 7)	T _C = +25°C	P _D	62	W
Thermal Resistance, Junction to Case (Note 7)		$R_{\theta JC}$	2	°C/W
Operating and Storage Temperature Range		$T_{J_i} T_{STG}$	-55 to +150	°C

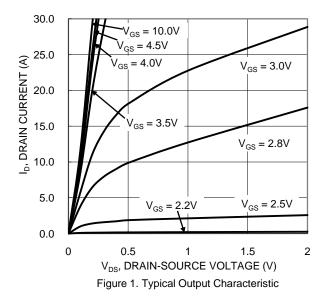
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

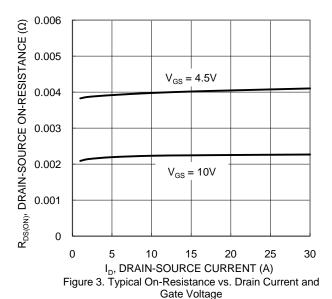
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	l		1	μΑ	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		_	±100	nA	$V_{GS} = +20V, V_{DS} = 0V$ $V_{GS} = -16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)						•	
Gate Threshold Voltage	V _{GS(TH)}	1	_	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		_	2.4	3.2	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	4	5.5		$V_{GS} = 4.5V, I_D = 15A$	
Diode Forward Voltage	V_{SD}	_	0.75	1	V	V _{GS} = 0V, I _S = 10A	
DYNAMIC CHARACTERISTICS (Note 9)			•				
Input Capacitance	C _{ISS}	_	2,370	_		V _{DS} = 15V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	_	1,360	_	pF		
Reverse Transfer Capacitance	C _{RSS}	_	240	_			
Gate Resistance	R _G	_	0.6	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Q_{G}	_	20	_			
Total Gate Charge (V _{GS} = 10V)	Q_{G}	_	44	_			
Gate-Source Charge	Q_GS	_	7	_	nC	$V_{DS} = 15V, I_{D} = 20A$	
Gate-Drain Charge	Q_{GD}	_	8	_			
Turn-On Delay Time	t _{D(ON)}	_	6.2	_		$V_{DD} = 15V, V_{GS} = 10V,$ $R_{L} = 0.75\Omega, R_{G} = 3\Omega, I_{D} = 20A$	
Turn-On Rise Time	t _R	_	4.3	_			
Turn-Off Delay Time	t _{D(OFF)}	_	21	_	ns		
Turn-Off Fall Time	t _F	_	8	_			
Body Diode Reverse Recovery Time	t _{RR}	_	25	_	ns		
Body Diode Reverse Recovery Charge	Q_{RR}	1	37		nC	$I_F = 15A$, di/dt = 500A/ μ s	

Notes:

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
 8. Short duration pulse test used to minimize self-heating effect.
 9. Guaranteed by design. Not subject to product testing.







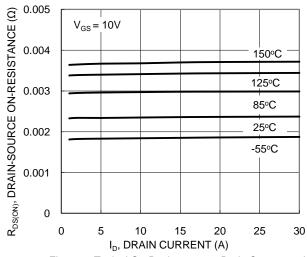


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

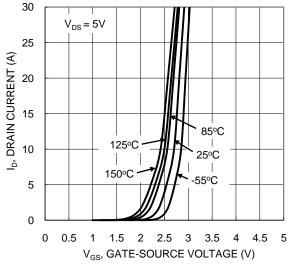
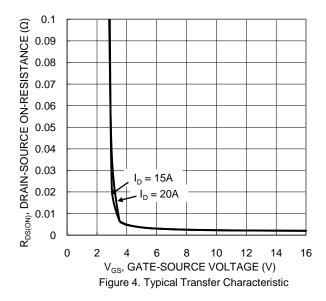


Figure 2. Typical Transfer Characteristic



R_{DS(ON)}, DRAIN-SOURCE ON-RESISTANCE (NORMALIZED) 2.5 2 $V_{GS} = 10V, I_{D} = 20A$ 1.5 1 $V_{GS} = 4.5V, I_{D} = 15A$ 0.5 0 -50 0 25 50 75 100 125 150 -25 T_J, JUNCTION TEMPERATURE (°C)

Figure 6. On-Resistance Variation with Junction Temperature



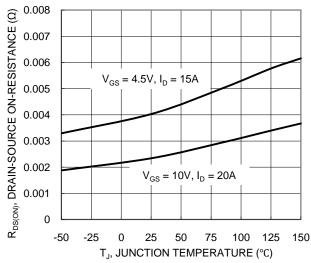


Figure 7. On-Resistance Variation with Junction Temperature

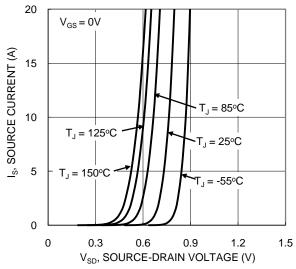


Figure 9. Diode Forward Voltage vs. Current

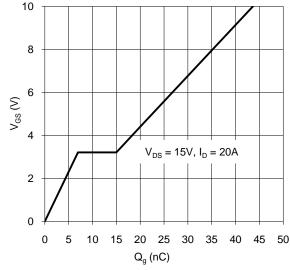


Figure 11. Gate Charge

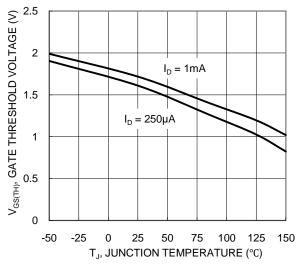
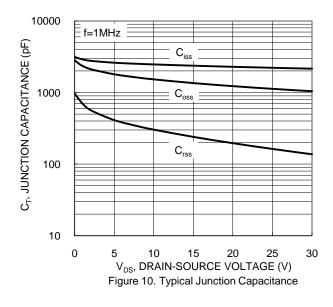
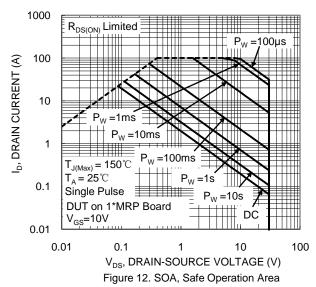


Figure 8. Gate Threshold Variation vs. Junction Temperature







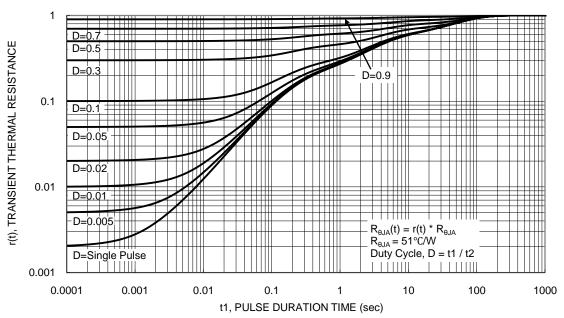


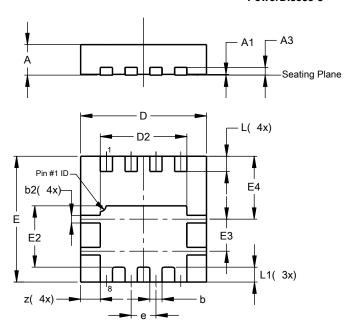
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

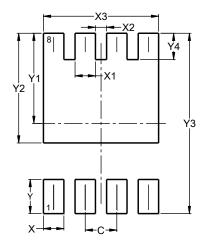


PowerDI3333-8						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	-	-	0.203			
b	0.27	0.37	0.32			
b2	0.15	0.25	0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
E	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
E3	0.79	0.89	0.84			
E4	1.60	1.70	1.65			
е	-	_	0.65			
L	0.35	0.45	0.40			
L1	_	_	0.39			
Z	_	_	0.515			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)
С	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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